



Refrigerator Fan Motor Driver

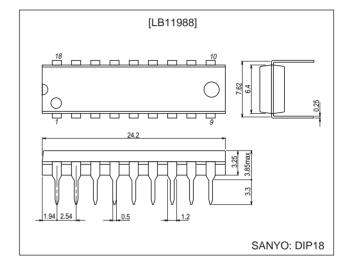
Functions

- Three-phase full-wave current linear drive
- · Built-in current limiter circuit
- Built-in saturation prevention circuits in both the upper and lower sides of the output stage.
- FG amplifier
- · Thermal shutdown circuit

Package Dimensions

unit: mm

3007A-DIP18



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum aupply voltage	V _{CC} max		24	V
Maximum supply voltage	V _S max		24	V
Maximum output current	I _{O max}		1.3	Α
Allowable power dissipation	Pdmax	Independent IC	1.13	W
Operating temperature	Topr		-30 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Cumply yeltogo	Vs		5 to 22	.,
Supply voltage	V _{CC}		7 to 22	V
Hall input amplitude	V _{HALL}	Between Hall inputs	±30 to ±80	mV 0-P

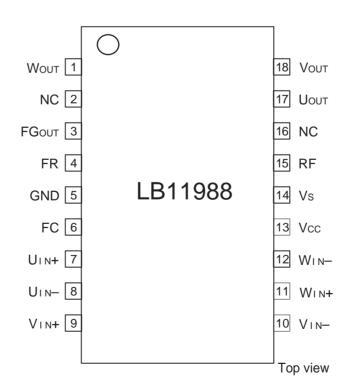
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Electrical Characteristics at $Ta=25^{\circ}C,\,V_{CC}$ = 12 $V,\,V_{S}$ = 12 V

Parameter	Symbol	Conditions	Ratings			Linia	
., .,		Conditions	min	typ	max	Unit	
V _{CC} current drain	Icc	$R_L = 560 \Omega (Y)$		15	24	mA	
[Output]	•						
Output saturation voltage	V _{Osat} 1	I_{O} = 500 mA, Rf = 0.5 Ω , Sink + Source (Saturation prevention function included)		2.1	2.6	V	
Output saturation voltage	V _{Osat} 2	$I_O = 1.0$ A, Rf = 0 Ω , Sink + Source (Saturation prevention function included)		2.6	3.5	V	
Output leakage current	I _{Oleak}				1.0	mA	
[Hall Amplifier]	•						
Input offset voltage	Voff (HALL)		-6		+6	mV	
Input bias current	I _b (HALL)	V _{IN} , W _{IN}		1	3	μΑ	
Common-mode input voltage	V _{cm} (HALL)		3		V _{CC} – 3	V	
[FR]							
Threshold voltage	V _{FRTH}		4		8	V	
Input bias current	lb(FR)		-5			μΑ	
[Current Limiter]							
LIM pin current limit level	I _{LIM}	$Rf = 0.5 \ \Omega,$ With the Hall input logic states fixed (U, V, W = high, high, low)		1		А	
[Saturation]							
Saturation prevention circuit lower side voltage setting	V _{Osat} (DET)	R_L = 560 Ω (Y), Rf = 0.5 Ω , The voltage between each lower output and the correspondi	ng Rf.	0.28		V	
[FG Amplifier]	•						
Upper side output saturation voltage	V _{satu} (SH)		11.8			V	
Lower side output saturation voltage	V _{satd} (SH)				0.3	V	
Hysteresis	Vhys			23		mV	
TSD operating temperature	T-TSD	Design target value*		170		°C	

Note \ast : Items shown to be design target values in the conditions column are not measured.

Pin Assignment



Truth Table and Control Functions

	Source → sink	Hall input			FR
	Source → Sink	U	V	W	FK
1	$V \rightarrow W$	Н	Н	_	Н
'	$W \rightarrow V$	П			L
2	$U \ \to W$	Н	L	-	Н
	$W \ \to U$	П	_	١	L
3	$U \ \to V$		L	Н	Н
3	$V \ \to U$	Н	L	П	L
4	$W \to V$	L		Н	Н
4	$V \rightarrow W$	L	_	Г	L
5	$W \ \to U$	L	-	Н	Н
) 2	$U \ \to W$	L	Н	-1	L
6	$V \rightarrow U$	1	Н	L	Н
	$V \rightarrow V$	_			L

Note: The "H" state for FR is defined as a voltage of 8 V or higher, and the "L" state for FR is defined as a voltage of 4 V or lower. (When V_{CC} = 12 V.)

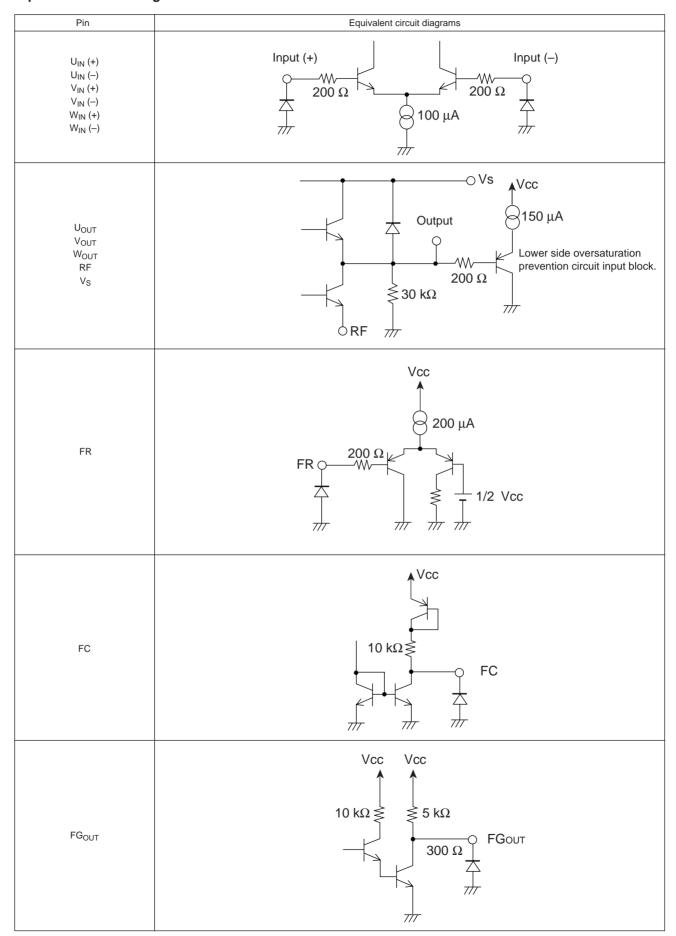
Note: For the Hall inputs, the input high state is defined to be the state where the (+) input is higher than the corresponding (-) input by 0.01 V or higher, and the input low state is defined to be the state where the (+) input is lower than the corresponding (-) input by 0.01 V or higher.

Note: Since this drive technique is a 180° current application scheme, the phases other than the sink and the source phases will not turn off.

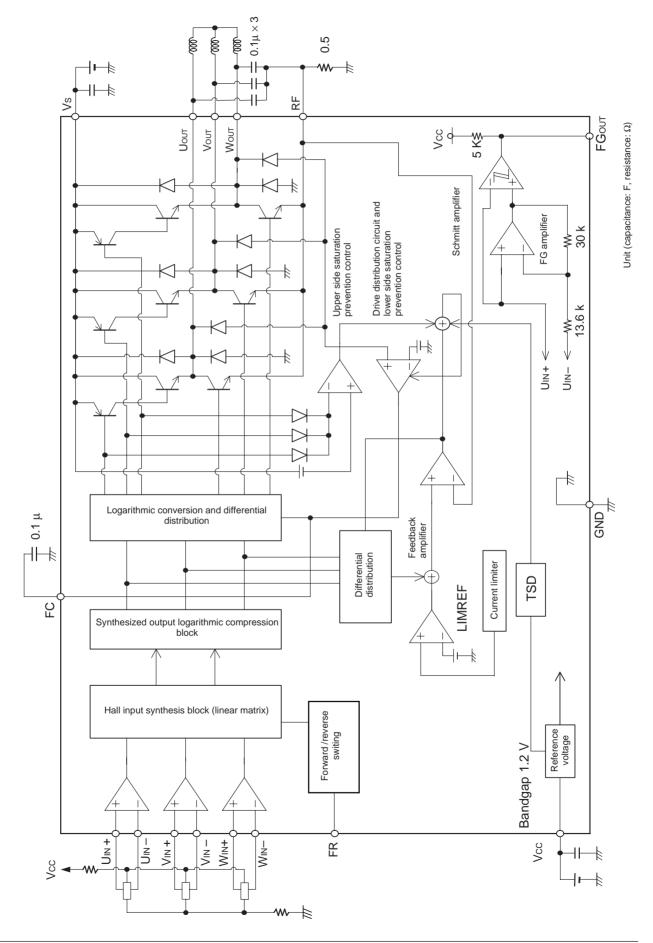
Pin Functions

Pin No.	Pin	Function		
5	GND	Ground for circuits other than the output transistors. Note that the Rf pin will be at the lowest potential of the output transistors.		
3	FG-OUT	This is the FG amplifier output pin. Internally, it is a resistive load.		
4	FR	Forward/reverse switching pin		
6	FC	Corrects the frequency characteristics of the saturation prevention circuit loop and current limiter circuit.		
7, 8	U _{IN} +, U _{IN} -	U-phase Hall input. Logic high refers to the state where IN+ > IN		
9, 10	V _{IN} +, V _{IN} -	V-phase Hall input. Logic high refers to the state where IN+ > IN		
11, 12	W _{IN} +, W _{IN} -	W-phase Hall input. Logic high refers to the state where IN+ > IN		
13	V _{CC}	Power supply provided to all IC internal circuits other than the output block. This voltage must be stabilized so that ripple and noise do not enter the IC.		
14	Vs	Output block power supply		
15	Rf	Used for output current detection. The current limiter circuit operates using the resistor (Rf) connected between this pin and ground. Note that the lower side saturation prevention circuit operates according to the voltage that appears on this pin. Since the over-saturation level is set by this voltage, the response of the lower side saturation prevention circuit may be degraded in the large current region if the value of Rf is made extremely small.		
17	U _{OUT}	U-phase Hall output		
18	V _{OUT}	V-phase Hall output (These pins include internal spark killer diodes.)		
1	W _{OUT}	W-phase Hall output		

Equivalent Circuit Diagrams



Block Diagram



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